## NSN 5961-00-075-7997

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View Online at https://aerobasegroup.com/nsn/5961-00-075-7997 **Inclosure Material:** Metal all transistor **Overall Length:** 0.410 inches all transistor **Terminal Length:** 1.500 inches all transistor **Overall Diameter:** 0.240 inches all transistor **Internal Configuration:** Junction contact all transistor **Internal Junction Configuration:** Pnp 2nd transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Semiconductor Material:** Germanium all transistor Voltage Rating In Volts Per Characteristic: 32.0 breakdown voltage, collector-to-base, emitter open all transistor **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 500.0 milliwatts total power dissipation all transistor **Terminal Type And Quantity:** 3 uninsulated wire lead all transistor Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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